

Vishay Siliconix

# N-Channel 80-V (D-S) MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A)		
80	0.0165 at V <sub>GS</sub> = 10 V	9.5		
	0.022 at V <sub>GS</sub> = 6.0 V	8.3		

#### **FEATURES**

• Halogen-free According to IEC 61249-2-21 Definition

> D Q

> > S

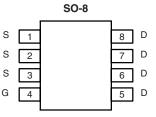
N-Channel MOSFET

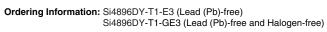
- TrenchFET<sup>®</sup> Power MOSFETs
- Compliant to RoHS Directive 2002/95/EC •

GO



Available





<b>ABSOLUTE MAXIMUM RATINGS</b> $T_A = 25 \degree C$ , unless otherwise noted					
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	80		V
Gate-Source Voltage		V <sub>GS</sub>	± 20		v
	T <sub>A</sub> = 25 °C	1	9.5 6.7		
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 70 °C	- I <sub>D</sub>	7.6	5.4	
Pulsed Drain Current		I <sub>DM</sub>	50		А
Avalanche Current	L = 0.1 mH	I <sub>AS</sub>	40		
Continuous Source Current (Diode Conduction) <sup>a</sup>		۱ <sub>S</sub>	2.8	1.4	
	T <sub>A</sub> = 25 °C	PD	3.1	1.56	W
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C	- <sup>-</sup> D	2.0	1.0	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
	t ≤ 10 s	R <sub>thJA</sub>	33	40	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		65	80	
Maximum Junction-to-Foot (Drain)	Steady State	R <sub>thJF</sub>	17	21	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

Top View

## Vishay Siliconix



<b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C, unless otherwise noted								
Parameter	Symbol	ool Test Conditions		Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \ \mu A$	2.0			V		
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA		
	1	$V_{DS} = 64 \text{ V}, V_{GS} = 0 \text{ V}$			1			
Zero Gate Voltage Drain Current	IDSS	$V_{DS}$ = 64 V, $V_{GS}$ = 0 V, $T_{J}$ = 55 °C			5	μΑ		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	50			А		
Drain-Source On-State Resistance <sup>a</sup>	Б	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 10 \text{ A}$		0.0135	0.0165			
	R <sub>DS(on)</sub>	$V_{GS} = 6.0 \text{ V}, \text{ I}_{D} = 8.0 \text{ A}$		0.0175	0.022	Ω		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 10 \text{ A}$		25		S		
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	$I_{\rm S} = 2.8$ A, $V_{\rm GS} = 0$ V		0.75	1.1	V		
Dynamic <sup>b</sup>				•	•			
Total Gate Charge	Qg			34	41			
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = 40$ V, $V_{GS} = 10$ V, $I_{D} = 10$ A		7.5		nC		
Gate-Drain Charge	Q <sub>gd</sub>			11.0		1		
Gate Resistance	Rg		0.2	0.85	1.2	Ω		
Turn-On Delay Time	t <sub>d(on)</sub>			17	25			
Rise Time	t <sub>r</sub>	$V_{DD}$ = 40 V, $R_L$ = 40 $\Omega$		11	17	1		
Turn-Off Delay Time	t <sub>d(off)</sub>	$\rm I_D \cong 1.0$ A, $\rm V_{GEN}$ = 10 V, $\rm R_g$ = 6 $\Omega$		40	60	ns		
Fall Time	t <sub>f</sub>			31	45			
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	$I_F = 2.8 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$		45	75			

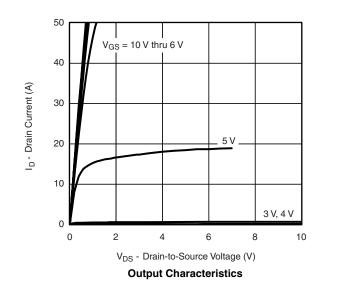
Notes:

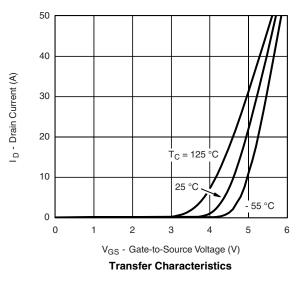
a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

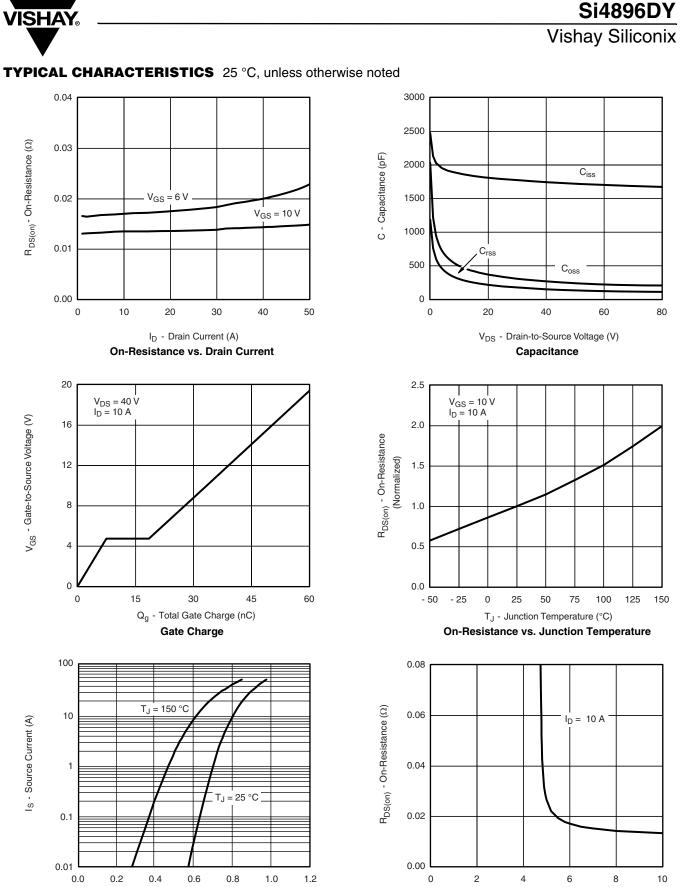
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







V<sub>SD</sub> - Source-to-Drain Voltage (V) Source-Drain Diode Forward Voltage

R  $_{\text{DS(on)}}$  - On-Resistance ( $\Omega)$ 

V<sub>GS</sub> - Gate-to-Source Voltage (V)

Is - Source Current (A)

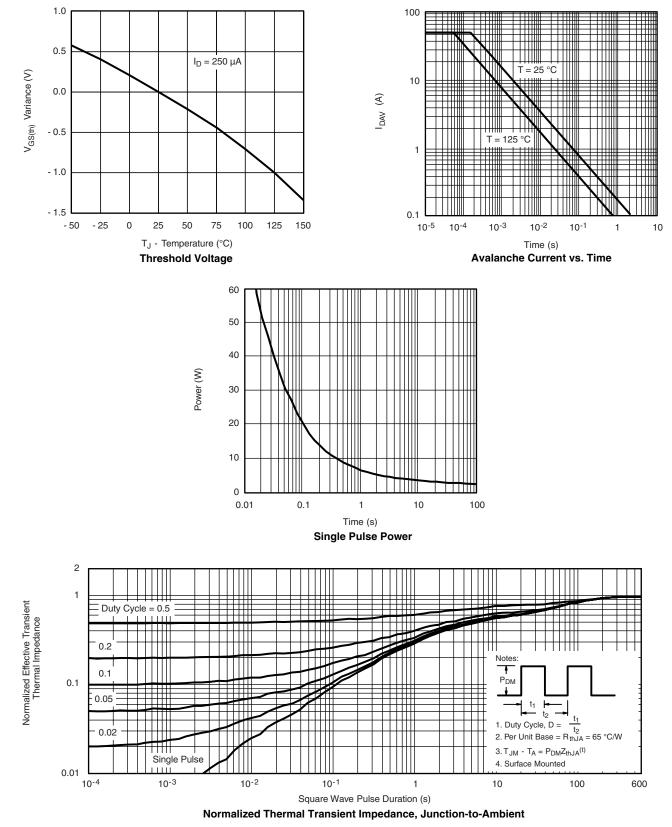
V<sub>GS</sub> - Gate-to-Source Voltage (V)

On-Resistance vs. Gate-to-Source Voltage

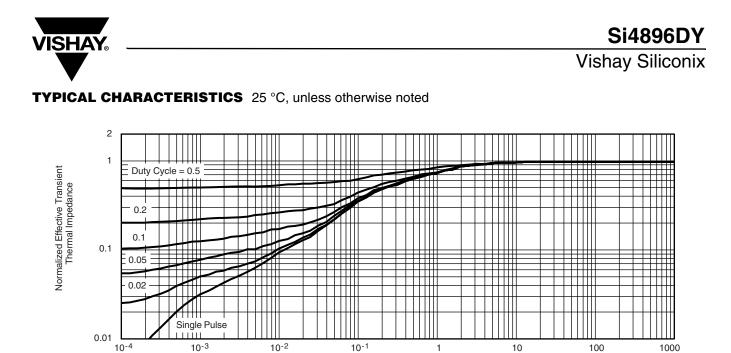
## Si4896DY

## Vishay Siliconix

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







Square Wave Pulse Duration (s) Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg271300">www.vishay.com/ppg271300</a>.



# Package Information

Vishay Siliconix

# SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012





	MILLIM	IETERS	INC	HES		
DIM	Min	Мах	Min	Max		
A	1.35	1.75	0.053	0.069		
A <sub>1</sub>	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
E	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498						

# **Application Note 826**

Vishay Siliconix



**RECOMMENDED MINIMUM PADS FOR SO-8** 



Recommended Minimum Pads Dimensions in Inches/(mm)

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